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Thyristor High Voltage, Phase Control SCR, 70 A



| PRODUCT SUMMARY | | | | |
|------------------------------------|------------------|--|--|--|
| Package | Super TO-247 | | | |
| Diode variation | Single SCR | | | |
| I _{T(AV)} | 70 A | | | |
| V _{DRM} /V _{RRM} | 1200 V, 1600 V | | | |
| V _{TM} | 1.25 V | | | |
| I _{GT} | 100 mA | | | |
| TJ | -40 °C to 125 °C | | | |

FEATURES

- High surge capability
- · High voltage input rectification
- Designed and qualified according to JEDEC[®]-JESD47
- Material categorization: For definitions of COMPLIANT compliance please see www.vishay.com/doc?99912

APPLICATIONS

- AC switches
- · High voltage input rectification (soft start)
- High current crow-bar
- Other phase-control circuits
- Designed to be used with Vishay input diodes, switches, and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-70TPS..PbF high voltage series of silicon controlled rectifiers are specifically designed for high and medium power switching, and phase control applications.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|------------------------------------|-------------------------------|------------|-------|--|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | | |
| I _{T(AV)} | Sinusoidal waveform | 70 | А | | | |
| I _{RMS} | Lead current limitation | 75 | ~ | | | |
| V _{RRM} /V _{DRM} | Range | 1200/1600 | V | | | |
| I _{TSM} | | 1100 | А | | | |
| V _T | 100 A, T _J = 25 °C | 1.4 | V | | | |
| dV/dt | | 500 | V/µs | | | |
| dl/dt | | 150 | A/µs | | | |
| TJ | | -40 to 125 | °C | | | |

| VOLTAGE RATINGS | | | | | | |
|-----------------|---|---|---|--|--|--|
| PART NUMBER | V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} /I _{DRM} AT 125 °C mA | | | |
| VS-70TPS12PbF | 1200 | 1300 | 15 | | | |
| VS-70TPS16PbF | 1600 | 1700 | 15 | | | |

Revision: 15-Apr-14 1 Document Number: 94391 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



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| ABSOLUTE MAXIMUM RATINGS | 5 | | | | | |
|---|------------------------------------|--|---|--|-------|------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average on-state current | I _{T(AV)} | $T_{C} = 82 \ ^{\circ}C, \ 180^{\circ} \ cond$ | $T_C = 82 \ ^{\circ}C$, 180° conduction half sine wave | | | |
| Maximum continuous RMS on-state current as AC switch | I _{T(RMS)} | Lead current limitation | Lead current limitation | | 75 | A |
| Maximum peak, one-cycle | I | 10 ms sine pulse, rate | d V _{RRM} applied | | 930 | |
| non-repetitive surge current | I _{TSM} | 10 ms sine pulse, no v | voltage reapplied | | 1100 | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rate | d V _{RRM} applied | Initial T _J = T _J maximum | 4325 | A ² s |
| | 1-1 | 10 ms sine pulse, no v | voltage reapplied | maximam | 6115 | |
| Maximum I²√t for fusing | l²√t | t = 0.1 ms to 10 ms, no | 61 150 | A²√s | | |
| Low level value of threshold voltage | V _{T(TO)1} | | | 0.916 | v | |
| High level value of threshold voltage | V _{T(TO)2} | T.I = 125 °C | 1.21 | v | | |
| Low level value of on-state slope resistance | r _{t1} | 1 j = 125 °C | | | 4.138 | mΩ |
| High level value of on-state slope resistance | r _{t2} | | | | | |
| Maximum peak on-state voltage | V_{TM} | 100 A, T _J = 25 °C | 100 A, T _J = 25 °C | | | V |
| Maximum rate of rise of turned-on current | dl/dt | T _J = 25 °C | | 150 | A/µs | |
| Maximum holding current | Ι _Η | Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C | | 200 | | |
| Maximum latching current | ١L | Anode supply = 6 V, resistive load, $T_J = 25 ^{\circ}\text{C}$ | | | 400 | |
| | I _{RRM} /I _{DRM} | T _J = 25 °C | V _B = Rated V _{BBM} /V _{DBM} | | 1.0 | mA |
| Maximum reverse and direct leakage current | | $T_J = 125 \text{ °C}$ ($T_J = T_J \text{ max., linear to 80 %}$ | | | 15 | |
| Maximum rate of rise of off-state voltage | dV/dt | T _J = 125 °C | $V_{DRM} = R_g - k = Open)$ | | 500 | V/µs |

| TRIGGERING | | | | | |
|---|--------------------|--|-----------------------------------|--------|-------|
| PARAMETER | SYMBOL | | TEST CONDITIONS | VALUES | UNITS |
| Maximum peak gate power | P _{GM} | T = 30 µs | T 00 | | w |
| Maximum average gate power | P _{G(AV)} | i = 30 μs | | 2.5 | vv |
| Maximum peak gate current | I _{GM} | | | 2.5 | А |
| Maximum peak negative gate voltage | - V _{GM} | | | 10 | |
| | V _{GT} | $T_J = -40 \ ^\circ C$ | | 1.8 | V |
| Maximum required DC gate voltage to trigger | | $T_J = 25 \ ^\circ C$ | Anode supply = 6 V resistive load | 1.5 | |
| | | T _J = 125 °C | | 1.1 | |
| | | T _J = - 40 °C | | 150 | |
| Maximum required DC gate current to trigger | I _{GT} | $T_J = 25 \ ^\circ C$ | Anode supply = 6 V resistive load | 100 | mA |
| | | T _J = 125 °C | | 80 | |
| Maximum DC gate voltage not to trigger | V _{GD} | | | 0.25 | V |
| Maximum DC gate current not to trigger | I _{GD} | T _J = 125 °C, V_{DRM} = Rated value 6 | | | mA |



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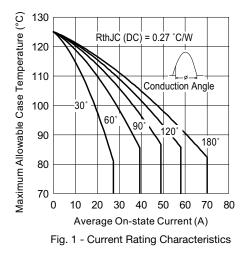
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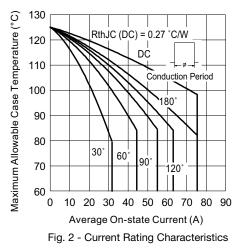
| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|---|----------------|-------------------|--------------------------------------|------------|------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction temperature | range | TJ | | -40 to 125 | °C | |
| Maximum storage temperature | range | T _{Stg} | | -40 to 150 | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation | 0.27 | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | | 40 | °C/W | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.2 | | |
| | | | | 6 | g | |
| Approximate weight | | | | 0.21 | oz. | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | |
| Mounting torque | maximum | | | 12 (10) | (lbf · in) | |
| | | | Casa at la Super TO 247 | 70TPS12 | | |
| | Marking device | | Case style Super TO-247 | 70TPS | 16 | |

| DEVICE | SINE HALF WAVE CONDUCTION RECTANGUL | | | | | | ULAR WAVE CONDUCTION | | | UNITS | |
|-------------|-------------------------------------|-------|-------|-------|-------|-------|----------------------|-------|-------|-------|-------|
| DEVICE | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | UNITS |
| VS-70TPSPbF | 0.078 | 0.092 | 0.117 | 0.172 | 0.302 | 0.053 | 0.092 | 0.125 | 0.180 | 0.306 | °C/W |

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC







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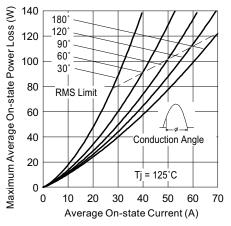
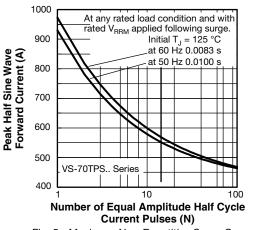


Fig. 3 - On-State Power Loss Characteristics





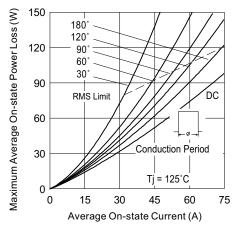


Fig. 4 - On-State Power Loss Characteristics

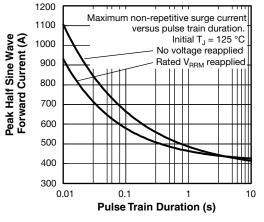
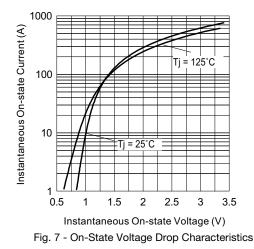
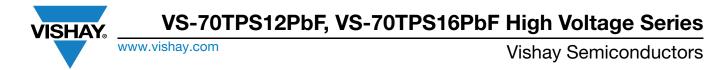


Fig. 6 - Maximum Non-Repetitive Surge Current





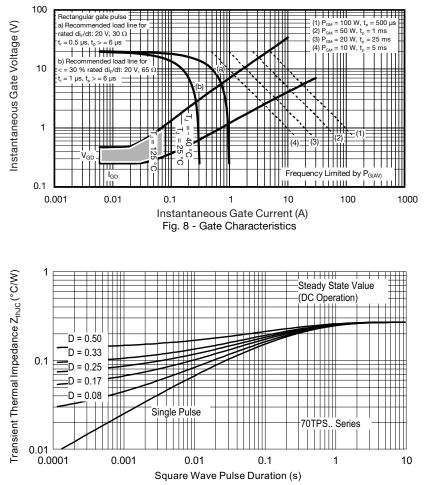


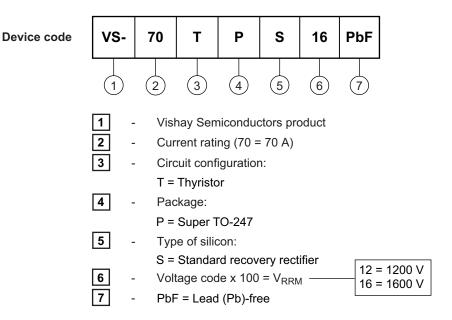
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE



| ORDERING INFORMATION (example) | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|
| PREFERED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-70TPS12PbF | 25 | 500 | Antistatic plastic tube | | | |
| VS-70TPS16PbF | 25 | 500 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?95073 | | | | | |
| Part marking information | www.vishay.com/doc?95070 | | | | |

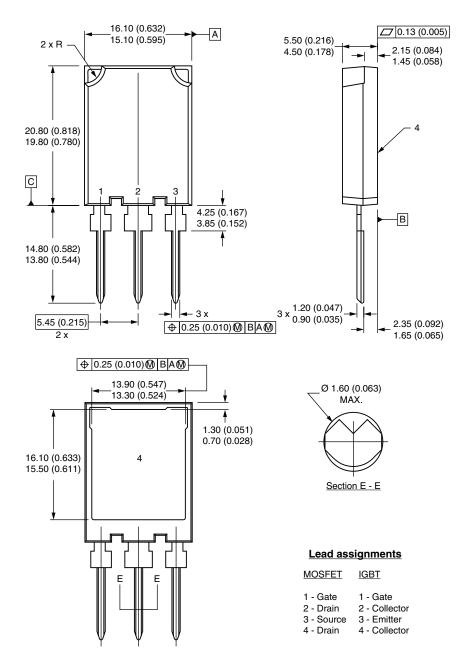


Vishay High Power Products

Super TO-247

DIMENSIONS in millimeters (inches)

ISHAY



Notes

- ⁽¹⁾ Dimension and tolerancing per ASME Y14.5M-1994
- ⁽²⁾ Controlling dimension: millimeter
- ⁽³⁾ Outline conforms to JEDEC outline TO-274AA



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